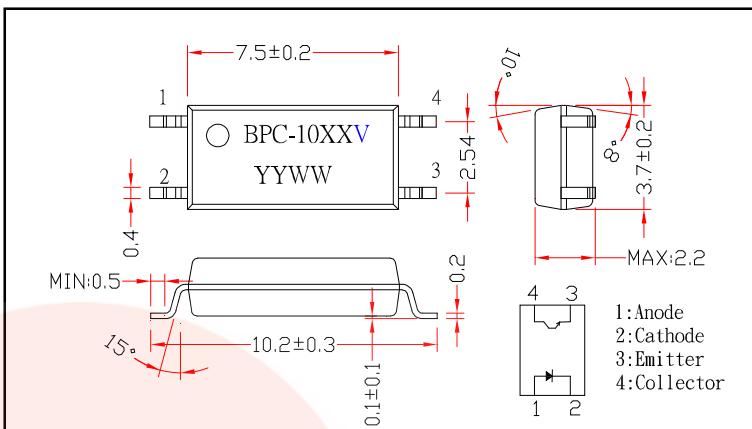




● Features:

1. Current transfer ratio:
(CTR:50~600% at $I_F=5\text{mA}$, $V_{CE}=5\text{V}$)
2. High input-output isolation voltage
($V_{iso}=5,000\text{Vrms}$)
3. Creepage distance >8mm
4. Long Mini-flat package:2.3mm profile
5. UL/CUL approved:E236324
6. VDE approved:40007240
7. CQC approved:CQC18001204187
8. This product doesn't contain restriction substance,comply RoHS standard

● Outline Dimensions



● Description

1. The BPC-10XX series are optically coupled isolators containing a infrared emitting diode and an NPN silicon phototransistor
2. The lead pitch is 2.54mm

● Applications:

1. Programmable controllers.
2. System appliances, measuring instruments.
3. Hybrid substrates that require high density mounting
4. Telecommunication equipments
5. Fast charger
6. Electric home appliances, such as fan heaters, etc.
7. Signal transmission between circuits of different potentials and impedances.

● NOTES:

- 1.XX: CTR Rank
- 2.YY: Year date code.
- 3.WW: 2-digit work week.
- 4.V: VDE option
- 5.All dimensions are in millimeters (inches).
- 6.Tolerance is $\pm 0.25\text{mm}$ (0.01") unless otherwise specified.

● Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Rating	Unit
INPUT	Forward Current	I_F	60	mA
	Reverse Voltage	V_R	6	V
	Power Dissipation	P	100	mW
OUTPUT	Collector-Emitter Voltage	V_{CEO}	80	V
	Emitter- Collector Voltage	V_{ECO}	7	
	Collector Current	I_C	50	mA
	Collector Power Dissipation	P_C	150	mW
Total Power Dissipation		P_{tot}	250	mW
*1 Isolation Voltage		V_{iso}	5,000	Vrms
Operating Temperature		T_{opr}	-30 to + 110	°C
Storage Temperature		T_{stg}	-55 to + 125	
*2 Soldering Temperature		T_{sol}	260	

*1. AC For minute, R.H. =40~60%

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

*2. For 10 Seconds



●Electro-Optical Characteristics (Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
INPUT	Forward Voltage	V _F	I _F =50mA	---	1.25	1.5	V
	Reverse Current	I _R	V _R =6V	---	---	10	μA
	Terminal Capacitance	C _t	V=0, f=1KHz	---	50	---	pF
OUTPUT	Collector Dark Current	I _{CEO}	V _{CE} =20V, I _F =0	---	---	100	nA
	Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =0.1mA I _F =0	80	---	---	V
	Emitter-Collector Breakdown Voltage	BV _{ECO}	I _E =100μA I _F =0	7	---	---	V
TRANSFER CHARACTERISTICS	Collector Current	I _c	I _F =5mA V _{CE} =5V	2.5	---	30	mA
	*1 Current Transfer Ratio	CTR		50	---	600	%
	Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _F =10mA I _C = 1mA	---	---	0.3	V
	Isolation Resistance	R _{iso}	DC500V 40~60%R.H.	5×10 ¹⁰	1×10 ¹¹	---	Ω
	Floating Capacitance	C _f	V=0, f=1MHz	---	0.6	1	pF
	Response Time(Rise)	t _r	V _{CE} =2V, I _C =2mA R _L =100Ω	---	---	18	μs
	Response Time(Fall)	t _f		---	---	18	μs

*1 CTR= $I_C / I_F \times 100\%$

●RANK TABLE OF CURRENT TRANSFER RATIO(CTR)

CTR Rank	Min	Typ	Max	Unit	Condition
BPC-1000	50	-	600	% I _F =5mA, V _{CE} =5V	I _F =5mA, V _{CE} =5V
BPC-1004	100		200		
BPC-1005	50		150		
BPC-1007	80	-	160		
BPC-1008	130	-	260		
BPC-1009	200	-	400		
BPC-1002	22	-	-	% I _F =1mA, V _{CE} =5V	I _F =1mA, V _{CE} =5V
BPC-1003	34	-	-		
BPC-1014	56	-	-		
BPC-1018	100		200		
BPC-1002	63	-	125	% I _F =10mA, V _{CE} =5V	I _F =10mA, V _{CE} =5V
BPC-1003	100	-	200		
BPC-1014	160	-	320		

● Characteristics Curves

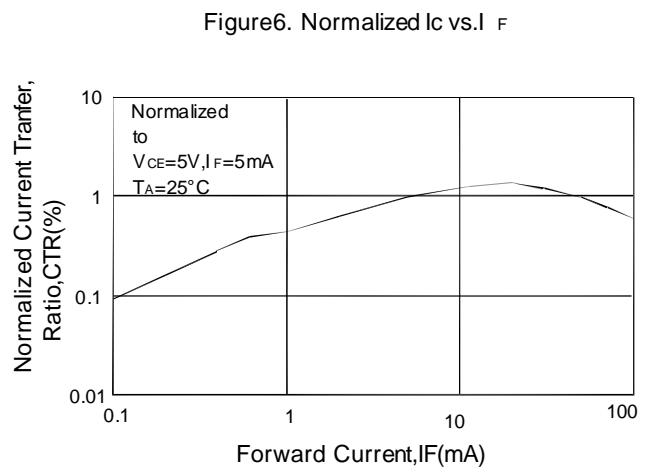
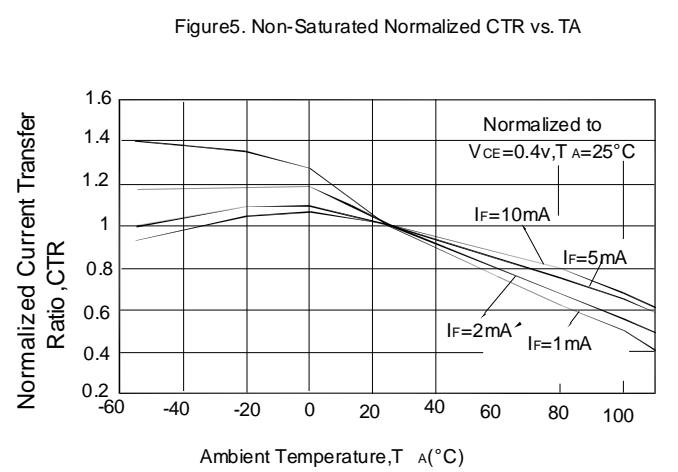
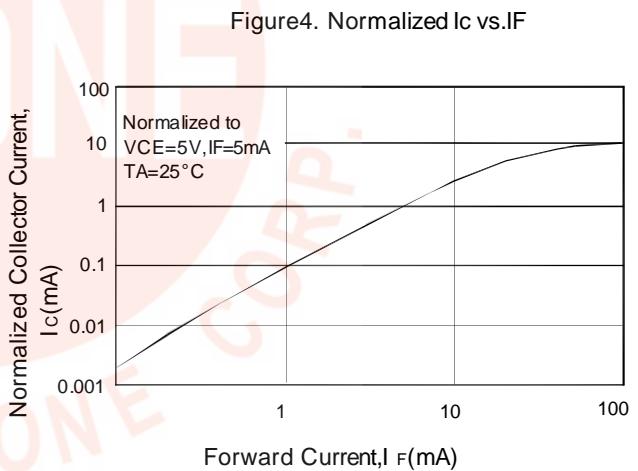
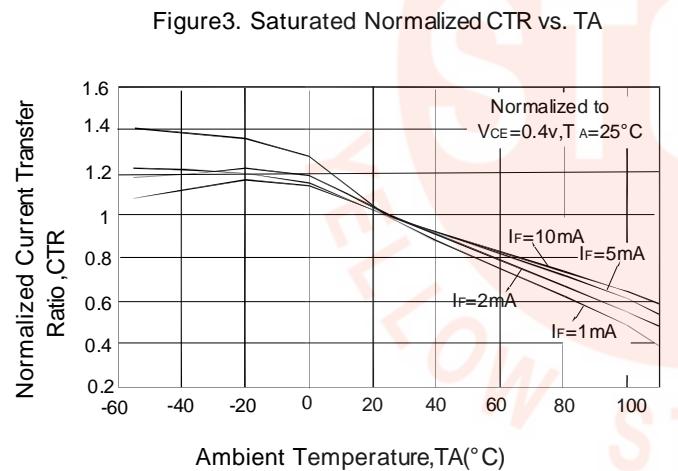
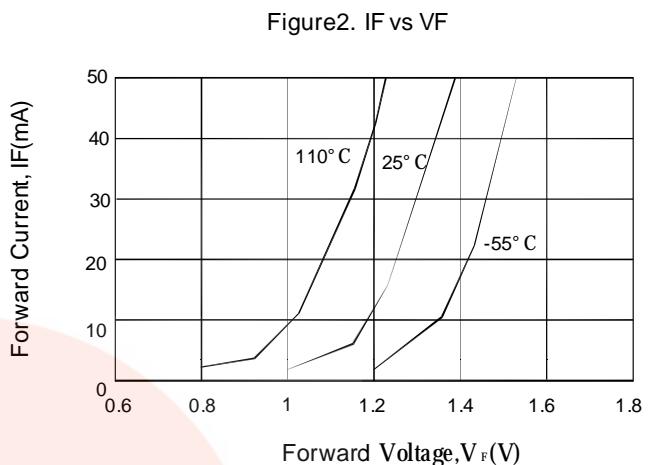
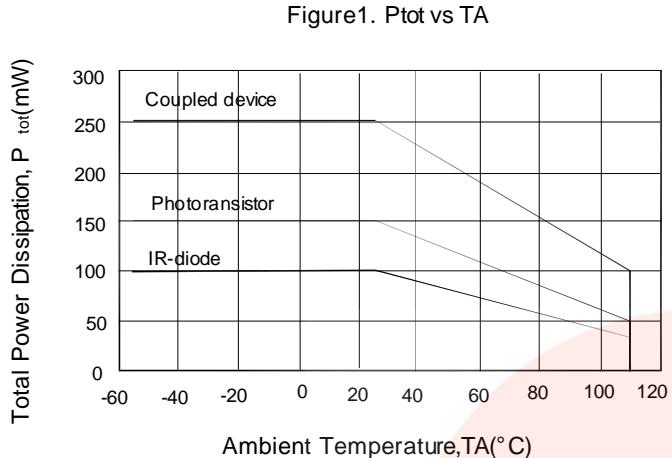




Figure7. I_{CEO} vs. T_A

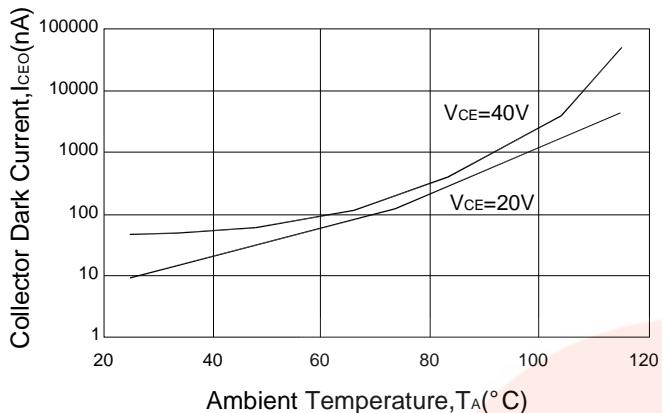


Figure8. T_{ON}/T_{OFF} vs. I_F

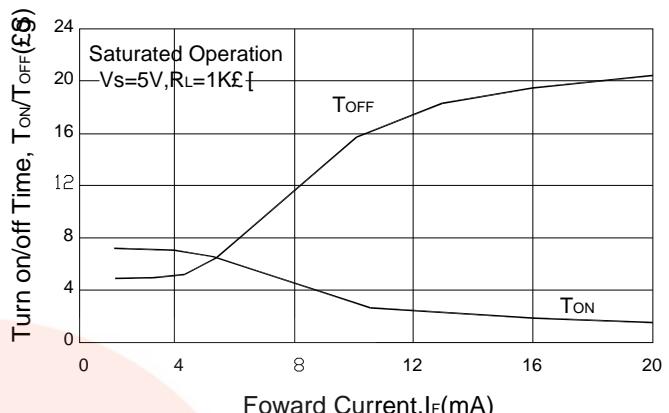


Figure9. I_C vs. V_{CE}

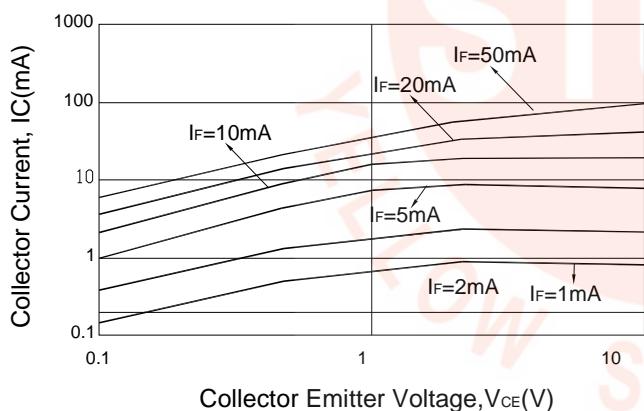


Figure10.Frequency Response

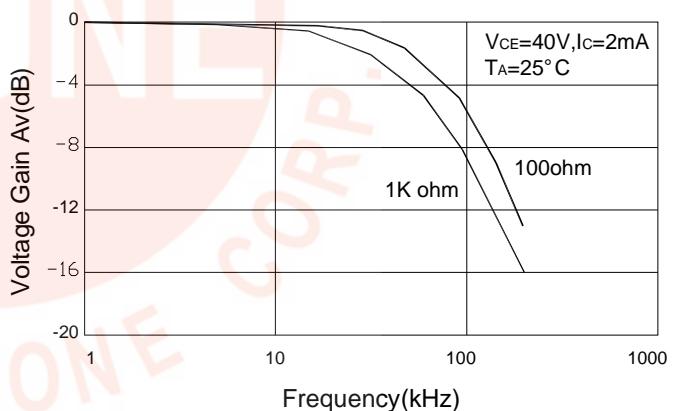
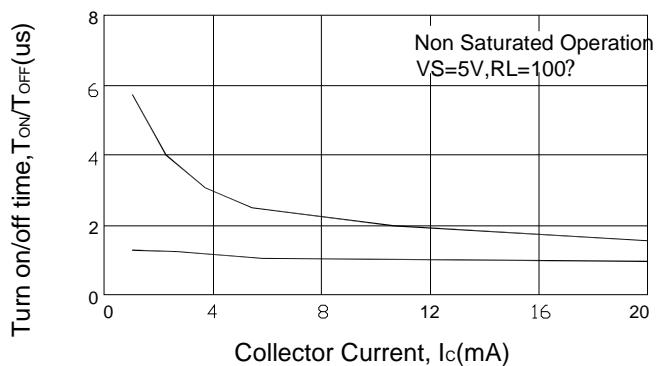
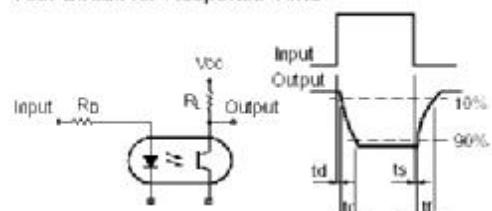


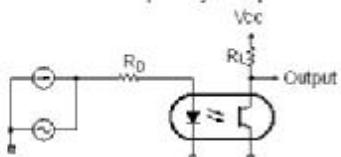
Figure11. T_{ON}/T_{OFF} vs. I_C



Test Circuit for Response Time



Test Circuit for Frequency Response



● Reliability Test

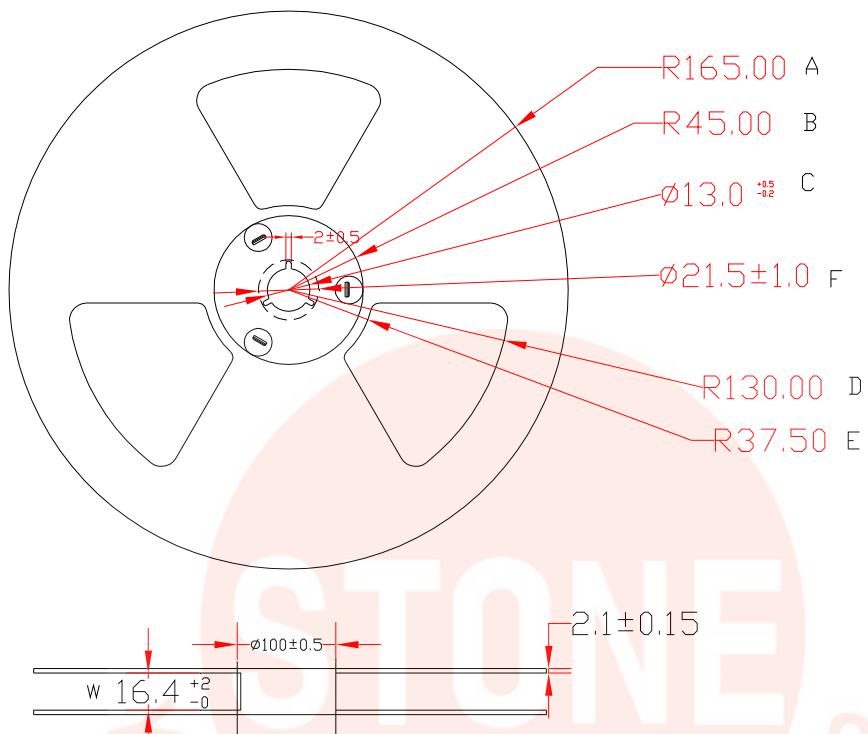
Classification	Test Item	Reference Standard	Test Conditions	Result
Endurance Test	Operation Life	MIL-STD-750:1026 MIL-STD-883:1005 JIS C 7021 :B-1	Connect with a power If=50mA Ta=Under room temperature Test time=1,000hrs	0/20
	High Temperature High Humidity Reverse Bias (H3TRB)	JIS C 7021 :B-11	Ta=+85°C±5°C, RH=85% PTR=V _{CE} absolute max rating*80% Test time=1000hrs	0/20
	High Temperature Reverse Bias (HTRB)	JIS C 7021 :B- 8	Ta=+105°C±5°C PTR=V _{CE} absolute max rating Test time=1000hrs	0/20
	High Temperature Storage	MIL-STD-883:1008 JIS C 7021 :B-10	High Ta=+125°C±5°C Test time=1,000hrs	0/20
	Low Temperature Storage	JIS-C-7021 :B-12	Low Ta=-55°C±5°C Test time=1,000hrs	0/20
	Autoclave	JESD 22-A102-B	P=15PSIG, Ta=121°C Humi. =100%RH, 48hrs	0/20
Environmental Test	Temperature Cycling	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1010 JIS C 7021 :A-4	125°C ~ 25°C ~ -55°C ~ 25°C 30min 5min 30min 5min Test Time=20cycle	0/20
	Thermal Shock	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1011	125°C ~-55°C 20min 20min Test Time=20cycle	0/20
	Solder Resistance	MIL-STD-202:201A MIL-STD-750:2031 JIS C 7021 :A-1	Operation heating : 260°C, within 10±1seconds.	0/20
	Solder Ability	MIL-S-883:2003 JIS C 7021 :A-2	Operation heating : 235°C, within 5±1seconds.	0/20

● Judgment Criteria Of Failure For The Reliability

Symbol	Measuring conditions	Judgment criteria for failure
V _F (V)	I _F =20mA	Over Ux1.0
I _r (uA)	V _r =6V	Over Ux1.0
CTR(%)	I _F =5mA, V _{CE} =5V	Shift>1.2
V _{CE(sat)}	I _F =20mA, I _C = 1mA	Over Ux1.0
BV _{CEO}	I _C =0.1mA, I _F =0	Over Lx1.0
BV _{ECO}	I _E =10μA, I _F =0	Over Lx1.0



● Packaging Box Dimensions (Units: mm)



I Packaging Tube Dimensions

